

<p>01 INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)</p> <p>NOV 20 2003</p> <p>PATENT &amp; TRADEMARK OFFICE U.S.A.</p>				Docket Number (Optional) <b>FUJI:141A</b>	Application Number <b>10/646,586</b>		
				Applicant(s) <b>Katsunori UENO</b>			
				Filing Date <b>August 22, 2003</b>	Group Art Unit <b>2811</b>		
<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILED DATE IF APPROPRIATE
<i>S</i>	US	<b>5,776,837</b>	<b>7/98</b>	<b>Palmour</b>	<b>438</b>	<b>767</b>	
<i>S</i>	US	<b>5,506,421</b>	<b>4/96</b>	<b>Palmour</b>	<b>257</b>	<b>77</b>	
<i>S</i>	US	<b>6,002,143</b>	<b>12/99</b>	<b>Terasawa</b>	<b>257</b>	<b>77</b>	
<b>FOREIGN PATENT DOCUMENTS</b>							
REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
<b>OTHER DOCUMENTS</b> (Including Author, Title, Date, Pertinent Pages, Etc.)							
<i>S</i>		"Vital Issues for SiC Power Devices"; K. Hara; Materials Science Forum Vols. 264-268 (1998); pgs. 901-906; 1998 Trans Tech Publications, Switzerland					
<i>S</i>		"High Voltage Planar 6H-SiC Accufet"; P.M. Shenoy et al.; Materials Science Forum Vols. 264-268 (1998); pgs. 993-996; 1998 Trans Tech Publications, Switzerland					
EXAMINER <i>Porraine Aho</i>		DATE CONSIDERED <b>4/2/04</b>					

**EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.**